ESD7002, SZESD7002

ESD Protection Diode

Low Capacitance ESD Protection Diode for High Speed Data Line

The ESD7002 surge protection device is designed to protect high speed data lines from ESD. Ultra−low capacitance and low ESD clamping voltage make this device an ideal solution for protecting voltage sensitive high speed data lines. The flow−through style package allows for easy PCB layout and matched trace lengths necessary to maintain consistent impedance between high speed differential lines such as USB 3.0 and HDMI.

Features
- Low Capacitance (0.3 pF Typical, I/O to GND)
- Diode capacitance matching
- Protection for the Following IEC Standards:
- IEC 61000−4−2 (Level 4)
- Low ESD Clamping Voltage
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q101 Qualified and PPAP Capable
- These Devices are Pb−Free and are RoHS Compliant

Typical Applications
- USB2.0/3.0
- LVDS
- HDMI
- High Speed Differential Pairs

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Operating Junction Temperature Range	T_J	−55 to +125	°C
Storage Temperature Range	T_{stg}	−55 to +150	°C
Lead Solder Temperature – Maximum (10 Seconds)	T_L	260	°C
IEC 61000−4−2 Contact (ESD) IEC 61000−4−2 Air (ESD)	ESD ESD	±8 ±15	kV kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
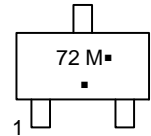
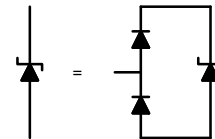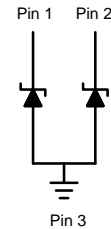## ON Semiconductor®
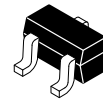
MARKING DIAGRAM

SC−70
CASE 419
STYLE 4

72 M∎

1

72 = Specific Device Code
M = Date Code
∎ = Pb−Free Package
(Note: Microdot may be in either location)

PIN CONFIGURATION AND SCHEMATIC

Pin 1 Pin 2

Pin 3

ORDERING INFORMATION

ESD7002, SZESD7002

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}	I/O Pin to GND			16	V
Breakdown Voltage	V_{BR}	I_T = 1 mA, I/O Pin to GND	16.5	23		V
Reverse Leakage Current	I_R	V_{RWM} = 5 V, I/O Pin to GND			1	μA
Clamping Voltage (Note 1)	V_C	IEC61000−4−2, ±8 kV Contact	See Figures 3 and 4			
Clamping Voltage TLP (Note 2)	V_C	I_{PP} = 8 A I_{PP} = 16 A I_{PP} = −8 A I_{PP} = −16 A		31.2 33.9 −5.5 −10.8		V
Junction Capacitance Match	ΔC_J	V_R = 0 V, f = 1 MHz between I/O1 to GND and I/O 2 to GND		5	10	%
Junction Capacitance	C_J	V_R = 0 V, f = 1 MHz between I/O Pins		0.2	0.4	pF
Junction Capacitance	C_J	V_R = 0 V, f = 1 MHz between I/O Pins and GND		0.3	0.5	pF
3dB Bandwidth	f_{BW}	R_L = 50 Ω		5		GHz

1. For test procedure see Figures 5 and 6 and application note AND8307/D.
2. ANSI/ESD STM5.5.1 – Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse (TLP) Model.
   TLP conditions: Z_0 = 50 Ω, t_p = 100 ns, t_r = 4 ns, averaging window; t_1 = 30 ns to t_2 = 60 ns.
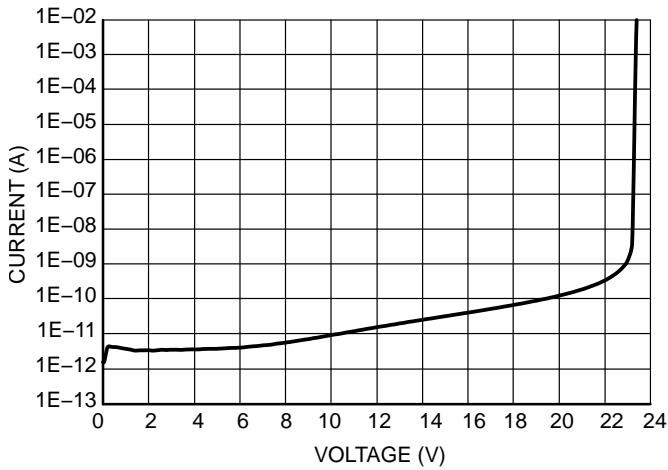

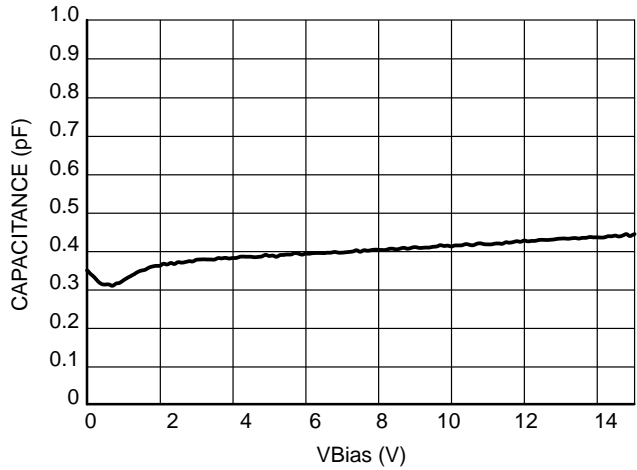Figure 1. Typical IV Characteristic Curve
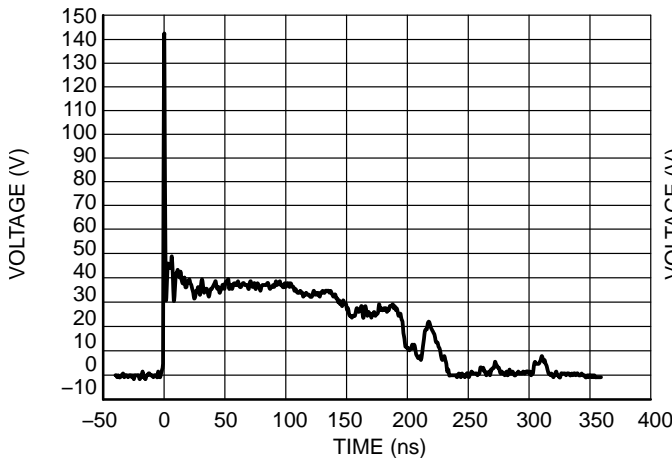

Figure 2. Typical CV Characteristic Curve

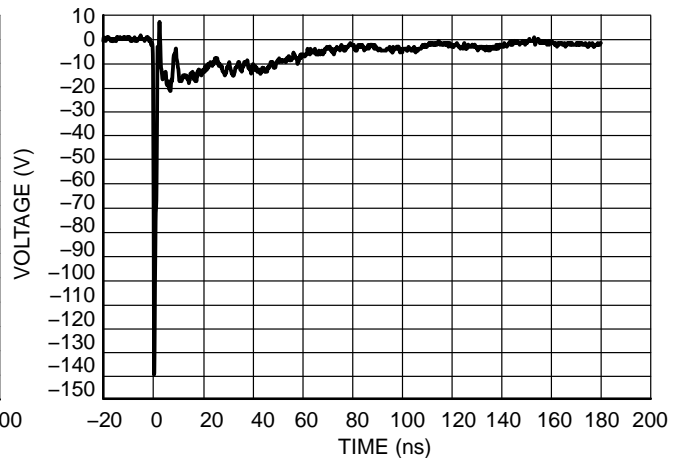

Figure 3. IEC61000−4−2 +8 kV Contact ESD Clamping Voltage

Figure 4. IEC61000−4−2 −8 kV Contact ESD Clamping Voltage

IEC 61000–4–2 Spec.

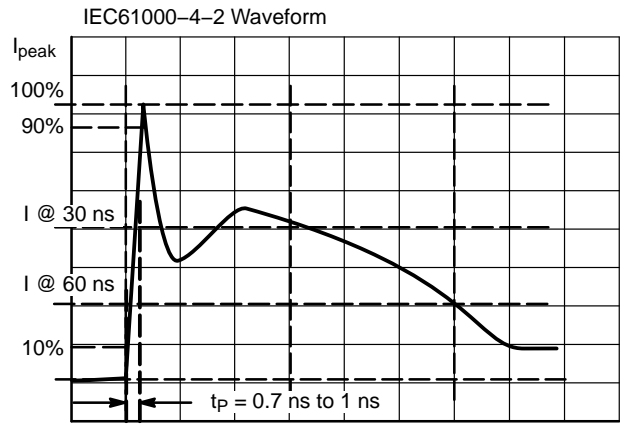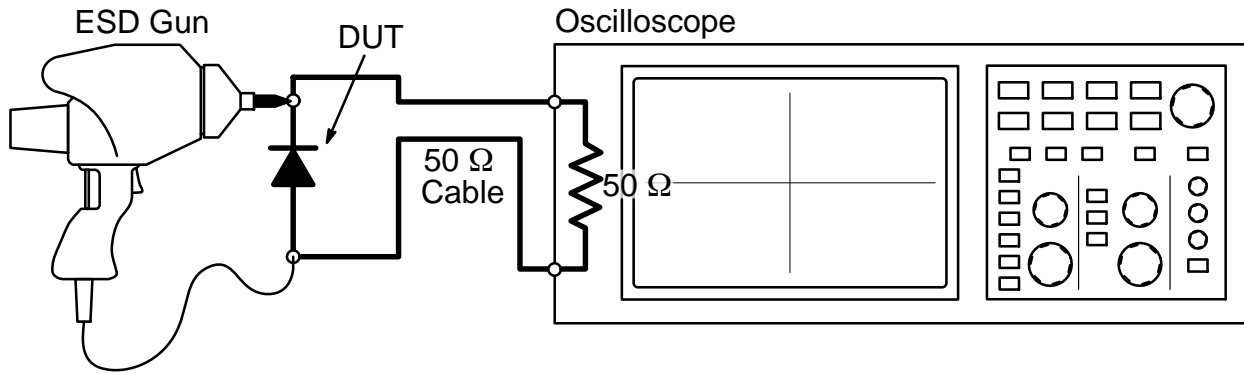| Level	Test Volt-age (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

Figure 5. IEC61000–4–2 Spec

Figure 6. Diagram of ESD Clamping Voltage Test Setup

The following is taken from Application Note AND8308/D – Interpretation of Datasheet Parameters for ESD Devices.

ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000–4–2 waveform. Since the IEC61000–4–2 was written as a pass/fail spec for larger systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.
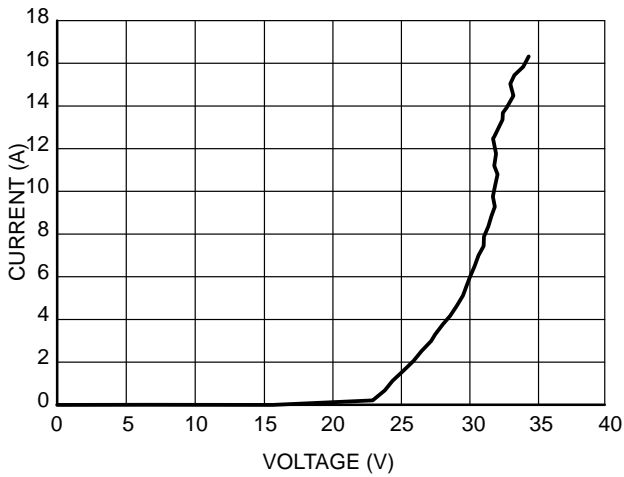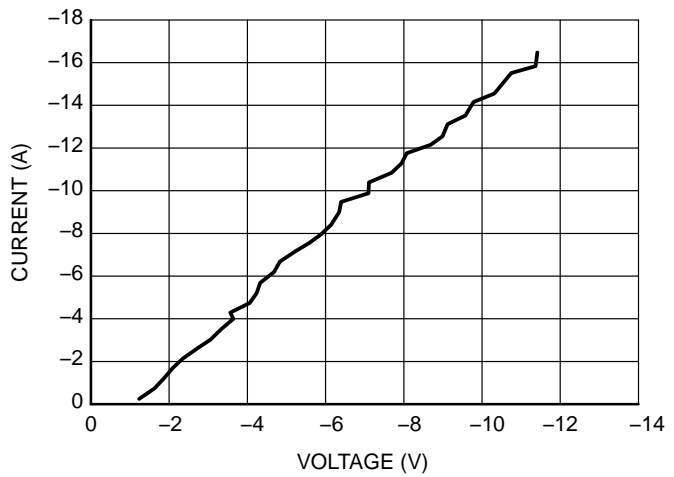
Figure 7. Positive TLP IV Curve

Figure 8. Negative TLP IV Curve

NOTE: TLP parameter: $Z_0 = 50 \Omega$, $t_p = 100$ ns, $t_r = 300$ ps, averaging window: $t_1 = 30$ ns to $t_2 = 60$ ns.

Transmission Line Pulse (TLP) Measurement

   Transmission Line Pulse (TLP) provides current versus voltage (I–V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 9. TLP I–V curves of ESD protection devices accurately demonstrate the product's ESD capability because the 10s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 10 where an 8 kV IEC 61000–4–2 current waveform is compared with TLP current pulses at 8 A and 16 A. A TLP I–V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels.
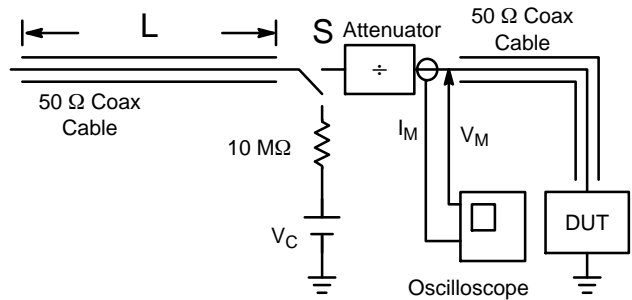
Figure 9. Simplified Schematic of a Typical TLP System
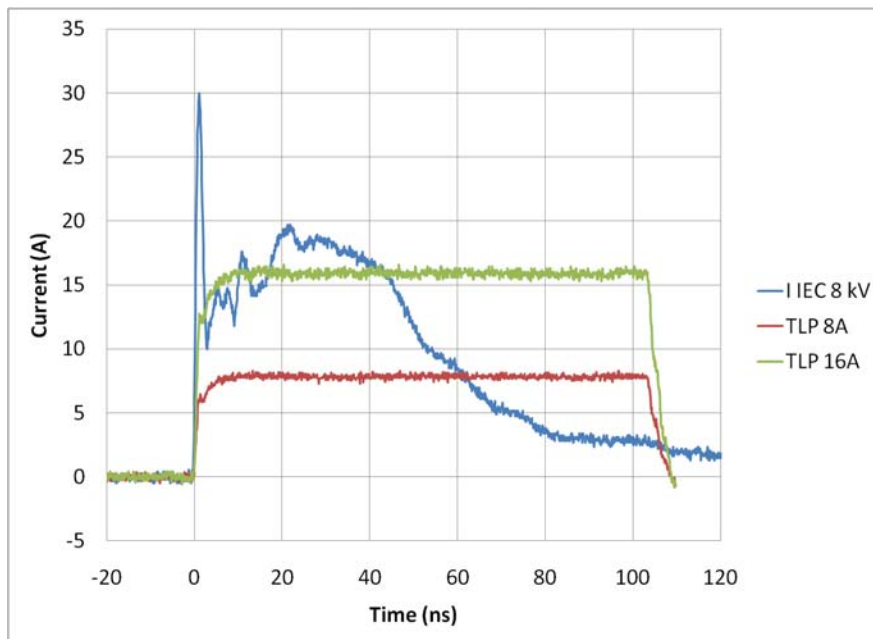
Figure 10. Comparison Between 8 kV IEC 61000–4–2 and 8 A and 16 A TLP Waveforms

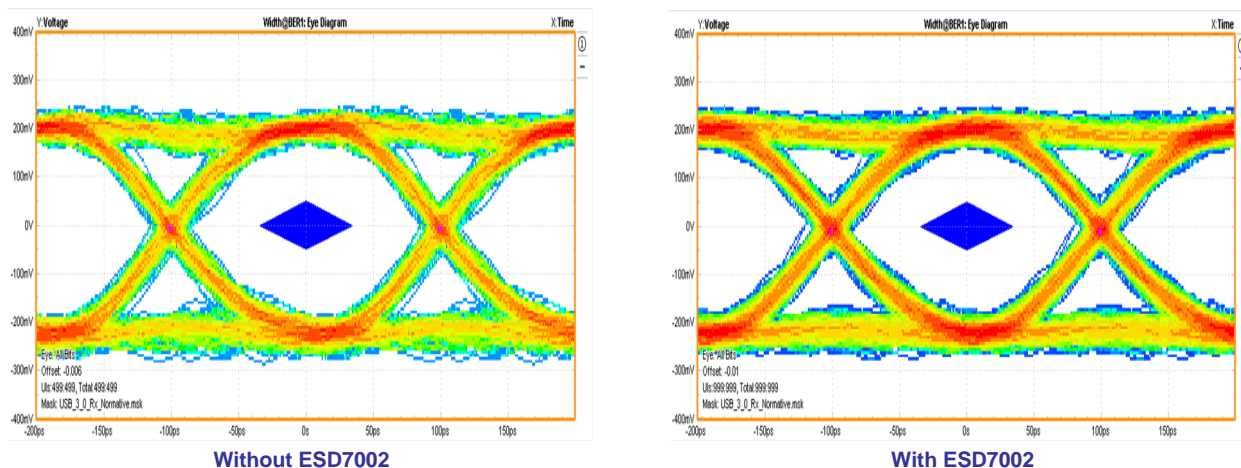Without ESD7002   With ESD7002
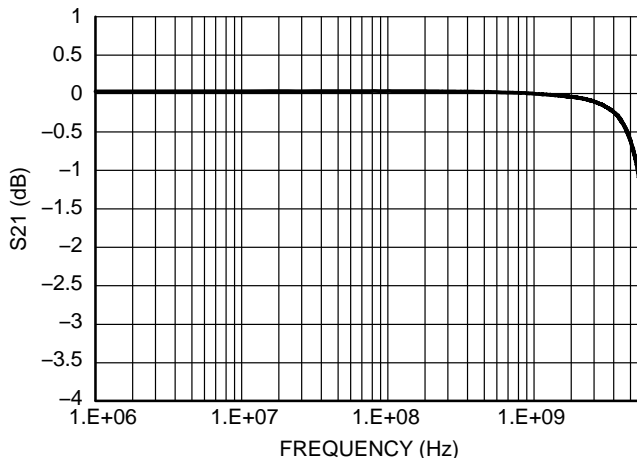
Figure 11. USB3.0 Eye Diagram with and without ESD7002 at 5 Gb/s


Figure 12. Typical Insertion Loss

ORDERING INFORMATION

Device	Package	Shipping†
ESD7002WTT1G	SC−70 (Pb−Free)	3000 / Tape & Reel
SZESD7002WTT1G*	SC−70 (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable.
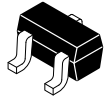
SC-70 (SOT-323)
CASE 419
ISSUE R

DATE 11 OCT 2022

SCALE 4:1

TOP VIEW

SIDE VIEW

0.05 (0.002)

END VIEW
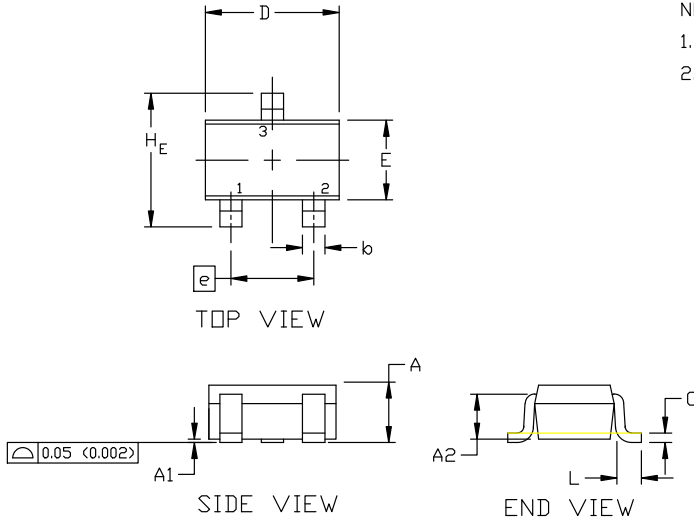
NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH

DIM	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 BSC		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.00	2.20	0.071	0.080	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
H_E	2.00	2.10	2.40	0.079	0.083	0.095

**GENERIC
MARKING DIAGRAM**

XX M■

1
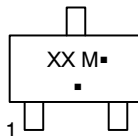
XX = Specific Device Code
M = Date Code
■ = Pb-Free Package

*This information is generic. Please refer to
device data sheet for actual part marking.
Pb-Free indicator, "G" or microdot "■", may
or may not be present. Some products may
not follow the Generic Marking.

0.65 [0.025]   0.65 [0.025]

1.90 [0.075]

0.90 [0.035]

0.70 [0.028]
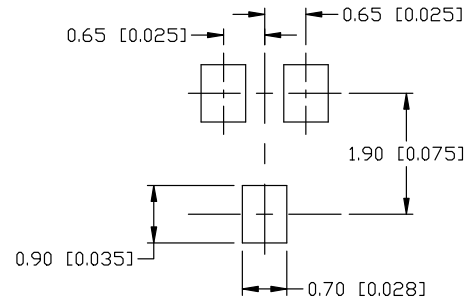
* For additional information on our Pb-Free
strategy and soldering details, please download
the ON Semiconductor Soldering and Mounting
Techniques Reference Manual, SOLDERRM/D.

SOLDERING FOOTPRINT

STYLE 1:
CANCELLED

STYLE 2:
PIN 1. ANODE
2. N.C.
3. CATHODE

STYLE 3:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 4:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 5:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 6:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 7:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 8:
PIN 1. GATE
2. SOURCE
3. DRAIN

STYLE 9:
PIN 1. ANODE
2. CATHODE
3. CATHODE-ANODE

STYLE 10:
PIN 1. CATHODE
2. ANODE
3. ANODE-CATHODE

STYLE 11:
PIN 1. CATHODE
2. CATHODE
3. CATHODE

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For additional information, please contact your local Sales Representative

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